Assembly of Cds nanoparticles on boron and fluoride co-doped TiO2 nanofilm for solar energy conversion applications†

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A highly crystalline mesoporous boron and fluoride (B/F) co-doped TiO2 nanomaterial is successfully synthetized using a facile process, followed by chemical bath deposition (CBD) in an organic solution to prepare the QD-cell to ensure high wettability and superior penetration ability of the B/F co-doped TiO2 films. A modified polysulfide redox couple, ([I(CH3)4N]2S/[I(CH3)4N]2S2−), was employed in a cadmium sulfide (CdS) quantum dot (QD)-sensitized B/F co-doped TiO2 solar cell covered with ZnS passivation layers with cobalt sulfide (CoS) as a counter electrode; then, an open-circuit photovoltage of 1.223 V, a high FF of 85.9%, a short-circuit photocurrent (Jsc) of 4.52 mA cm−2, and a high overall energy conversion of 4.74% were obtained.

1. Introduction

Quantum-dot-sensitized solar cells (QDSSCs), as a derivative of dye-sensitized solar cells (DSCSs), have attracted extensive attention in recent years due to their higher theoretical conversion efficiency and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCs11−18 as inorganic QDs exhibit various advantages over organic dyes, such as easy obtainability, low cost, high molar extinction coefficients, and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCs11−18 as inorganic QDs exhibit various advantages over organic dyes, such as easy obtainability, low cost, high molar extinction coefficients, and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCs11−18 as inorganic QDs exhibit various advantages over organic dyes, such as easy obtainability, low cost, high molar extinction coefficients, and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCs11−18 as inorganic QDs exhibit various advantages over organic dyes, such as easy obtainability, low cost, high molar extinction coefficients, and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCs11−18 as inorganic QDs exhibit various advantages over organic dyes, such as easy obtainability, low cost, high molar extinction coefficients, and lower production costs. Recently, a series of QDs (CdS, CdSe, PbS, CdSe0.5Te0.5, and CuInS2) and their derivatives1−19 were employed as light-absorber sensitizers. The metal-oxide semiconductor (TiO2) film electrode, electrolyte as well as counter electrode were also systematically optimized to improve the performance of QDSSCS

Qds: 1.223 V, FF: 85.9%, Jsc: 4.52 mA cm−2, η: 4.74%

The theoret-ical conversion efficiency of QDSSCs is as high as 44%,11,17 which makes the QDs prominent candidates for application in solar cells. However, the photovoltaic conversion efficiency of QDSSCs is still lower than that of the DSSCs because of the severe recombination of electrons of the quantum dot conduction band. Recent advances in quantum dot solar cells (QDSSCs) have propelled them to the forefront of the photovoltaic research, for power conversion efficiencies (PCEs) in excess of 11% that have been achieved by Zhong’s group.22 This is a new record efficiency for QD solar cells in any configuration and also a new record for QDSSCs with any QD sensitizer. To date, the highest reported efficiency of CdS (QDSSCs) using I−/I3− based electrolyte and Pt counter electrode is 1.84%,24

In the past few years, there has been a considerable effort to enhance the energy conversion efficiencies of QDSSCs using various strategies. A review of the literature indicates that much of the research in QDSSCs has been focused on the synthesis of various structures of photoanodes,25,26 sensitizing the photoanodes with various combinations of QDs,27,28 depositing QDs on an anode with various chemical methods,29 and changing the chemical composition of the redox electrolyte.30−34 With an important role in QDSSCs, TiO2 films act as the support for QD loading and charge transport medium, and thus numerous studies have been carried out to exploit efficient TiO2 nanostructures.35−37 Chen et al. fabricated a novel double-sided CdS quantum-dot-sensitized TiO2 nanotube (TNT)/ITO photoelectrode, and the experimental results show that the double-sided CdS quantum-dot-sensitized NT/ITO photoelectrodes show enhanced light absorption and achieve an optimum conversion efficiency of 7.5%, which is an enhancement of about 120% when compared with the single-sided CdS/TNT/Ti photoelectrode.38 In either DSCs or QDSSCs, the nanoparticle porous film electrode plays a key role in the improvement of power conversion efficiency. However, TiO2 is a large band gap semiconductor (Eg = 3.2 eV), which can only be excited by UV radiation at a wavelength below 390 nm. To make better use of the full light spectrum, doping TiO2 with metal and nonmetal elements has

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been considered as a promising way to tailor the electronic properties of TiO$_2$ photoanodes in QDSSCs and has succeeded in improving photovoltaic performance of QDSSCs. In particular, non-metallic doping of TiO$_2$ electrodes has attracted much attention due to the excellent performance of the resulting doped material. Moreover, the technology of co-doping has been proven to be an effective solution to improve the performance of the TiO$_2$ electrodes due to its charge compensation on the basis of different ions through an internal charge transfer, with a large stabilization effect resulting in a less defective co-doped TiO$_2$ system.$^{39,40}$

To the best of our knowledge, research into non-metallic B/F co-doping in QDSSCs has not been systematically carried out. Therefore, it would be highly desirable to research the co-doping effect on QDSSC systems. Herein, we investigated the effect of B/F co-doping on the QDSSC’s performance and demonstrated that the application of a B/F co-doped TiO$_2$ electrode in QDSSCs can enhance the photovoltaic performance of QDSSCs. In this study, we report the first example of CdS quantum dot (QD)-sensitized B/F co-doped TiO$_2$ solar cells with ZnS passivation layers using CoS as a counter electrode. The configuration of the cells is illustrated in Scheme 1. As a result, a CdS QD-sensitized B/F co-doped TiO$_2$ solar cell using the same ((CH$_3$)$_2$N)$_2$S/((CH$_3$)$_2$N)$_2$S$_4$ electrolyte shows a promising photovoltaic performance, with an efficiency of 4.74%, a significantly high $V_{oc}$ of 1.223 V, and a high FF of 85.9% with a short-circuit photocurrent ($J_{sc}$) of 4.52 mA cm$^{-2}$.

2. Experimental

2.1 Preparation of B–F co-doped TiO$_2$ nanoparticles

The doped and modified nanocrystalline powder was synthesized using the sol–gel route, followed by pyrolysis and calcination treatments. Titanium tetraisopropoxide (Ti(Oi-Pr)$_4$) (Alfa Aesar), acetylacetone (acac, Aldrich), boron fluoride acetic acid complex (BF$_3$·2CH$_3$CO$_2$, 97%), and tetrafluorboric acid (HBF$_4$, 48%, Strem Chemicals, Newburyport, MA) were used as received. An alcoholic complex was prepared by slowly adding BF$_3$·2CH$_3$CO$_2$ (0.03 mol) to 10 mL of EtOH at 0 °C under ambient conditions, which formed a homogeneous and viscous solution. Once this solution cooled to room temperature, it was slowly added to Ti(Oi-Pr)$_4$ (0.07 mol) in 10 mL iPrOH, producing a vivid yellow homogeneous solution. After the mixture was stirred for 15 min, deionized water (500 mL) was added, which brought no discernible change; hence 100 mL of HBF$_4$ was added, and after a few minutes, the yellow solution became turbid. It was then refluxed at 80 °C for 30 min, which effectively rehomogenized the mixture (pH: 1–2). After the mixture was refluxed for 6 h at 70 °C, Ti(Oi-Pr)$_4$ (0.069 mol) was added to the reaction vessel to facilitate particle formation, and refluxing was continued for 18 h at 70–80 °C while stirring. The volume of the solution was reduced to approximately one-fifth, yielding a finely dispersed white powder. The powder was separated by filtration through a medium porosity ceramic frit, repeatedly washed with water until the pH of the filtrate was neutral and finally dried at 100 °C in an oven.

The as-synthesized material was subjected to different thermal treatments. Specifically, the purified powder was placed in a borosilicate test tube, which was attached to a glass manifold employing Cajon connectors and stainless steel tubing, and was heated to 400 °C (4 °C min$^{-1}$). A short ceramic oven was employed to allow manipulation of the sample tube while it was still connected to the manifold. The sample’s appearance was monitored visually over the course of the heating procedure, and the temperature was increased to 500 °C while under vacuum or under gas flow for periods of up to 3 h. The heavily reduced powder, on the basis of its coloration (gray), was exposed briefly to air by opening the vessel to the atmosphere or to pure oxygen gas that was delivered directly to the sample container. The final stage of the thermal treatment consisted of the evacuation of the tube’s contents or rapidly cooling it to 100 °C while in air.

2.2 Deposition of CdS QD-sensitized B–F co-doped TiO$_2$ solar cells

The B–F co-doped TiO$_2$ (B–F–TiO$_2$) oxide used in the front subcell electrode was individually mixed with a polymer binder, and dissolved in terpineol, resulting in a paste. The paste was then coated on the fluorine-doped (FTO) SnO$_2$ conductive glass (TEC15, 15 Ω per square, Pilkington, USA) by screen printing and then dried for 5 min at 125 °C. This procedure was repeated 4 times (to give ca. 8 μm film). The electrodes were gradually heated at 500 °C for 30 min, and the sintered film was further treated with 40 mM TiCl$_4$ aqueous solution at 70 °C for 30 min, washed with ethanol and water, and annealed at 480 °C for 30 min. SILAR was used to assemble CdS-QDs into the B–F–TiO$_2$ photoelectrode. B–F–TiO$_2$ films were surface-modified by immersing in 0.1 M mercaptoacetic acid (TGA) for 1 min; the TGA-modified B–F–TiO$_2$ substrate electrode was dipped first into an ethanol solution containing Cd(NO$_3$)$_2$ (0.5 M) for 1 min, rinsed with ethanol, and dried with an air gun. The electrodes were then dipped for another 1 min into a Na$_2$S methanol solution (0.5 M) and rinsed again with methanol. The process was repeated up to N cycles (N = 1 to 5). These as-prepared electrodes are represented herein as “B–F–TiO$_2$/TGA/CdS–N” electrodes.” The CdS-sensitized B–F–TiO$_2$ films were coated with ZnS for 3 cycles by dipping alternately into 0.1 M Zn(OAc)$_2$ methanol solution and 0.1 M Na$_2$S solutions for 1 min per dip. As the working electrode, CoS was separated with a hot-melt Surlyn 1702 film (25 μm, DuPont). Cleaned FTO glass was
dipped into 0.5 M Co(NO₃)₂ ethanolic solution for 30 s, rinsed with ethanol, and dried with an air gun. The sample was then dipped for 30 s into 0.5 M Na₂S methanolic solution, followed by rinsing with methanol and drying with an air gun. The process was repeated for up to five cycles to obtain the CoS electrode. The electrolyte solution consisting of 0.01 M tetramethyl ammonium sulfide ((CH₃)₄N)₂S, 0.002 M S, 0.02 M LiClO₄, 0.02 M 4-tert-butylpyridine (TBP), 3-methoxypropionitrile (MPN) was used as a solvent for the polysulfide electrolyte. The ((CH₃)₄N)₂S was prepared by heating tetramethyl ammonium hydroxide ((CH₃)₄N)OH and ammonium sulfide (NH₄)₂S at 100 °C. We investigated three experiment samples with the same conditions five times to test the repeatability and stability of the experiment, which gave excellent results.

3. Optical and photovoltaic measurements

Crystal structures of the samples were analyzed by X-ray diffraction (XRD) (Japan, XD-3A) using Cu Kz radiation and a scintillation counter detector. The patterns were recorded in the 2θ range of 20–80°. The elemental distribution and concentration were analyzed by an energy dispersive spectrometer (EDS) (Oxford Inc) attached to the field emission scanning electron microscope (FESEM). UV-vis absorption spectra were recorded on a UV-visible spectrometer (U-4100, HITACHI, Japan). The electronic structure and B–F-doping amount was determined by X-ray photoelectron spectroscopy (XPS) (AXIS-165 Shimadzu, Japan). Transmission electron microscopy (TEM) images were obtained using a JEOL JEM-2100 instrument. The flat-band potential (Vₓb) of the nanostructured TiO₂ and B–F–TiO₂ electrode was determined by measuring the absorbance at 780 nm as a function of the applied potential. For the spectroscopic electrochemistry measurement, an 8 µm thick TiO₂ film formed the working electrode (1 cm² surface area) of a three-electrode photoelectrochemical cell employing a platinum wire counter electrode and an Ag/AgCl reference electrode. Potential control was carried out on a CHI 660E potentiostat, and an impedance/gain-phase analyzer (ZENIUM, ZAHNER, Germany). The spectral regions were scanned using a frequency range of 10⁻¹ to 10⁷ Hz at room temperature. The alternate current (AC) amplitude was set at 10 mV.

4. Results and discussion

4.1 Optical properties

Fig. 1 shows that the absorbance intensity of these films increases with noticeable shifts of the absorbance edge towards longer wavelength, and a shoulder to the visible light region was observed with doped B and F, where the film doped with B and F shows yellow colour while the undoped film shows white colour. The UV-vis absorption spectra of the B–F-doped TiO₂/TGA/CdS-3 film and the TiO₂/TGA/CdS-3 film in the ((CH₃)₄N)₂S/(CH₃)₄N)S₈ electrolyte also shifted about 30 nm to longer wavelength, which is beneficial for for the B–F-doped TiO₂/TGA/CdS-3 film to capture more light and to obtain higher light to electrical efficiency.

4.2 Spectro-electrochemical properties

In order to further investigate the cause of the enhancement of Vₙc in QDSSCs, the spectro-electrochemical measurements for undoped and B/F co-doped TiO₂ were carried out, and the results are shown in Fig. 2. The flat-band potential Vₙb of TiO₂ samples with and without B/F co-doping were determined as −2.2 V and −2.097 V (vs. Ag/AgCl), respectively. Therefore, a higher quasi-Fermi level closer to the conduction band was definitely achieved, which could lead to the larger Vₙc for liquid-state QDSSCs employing a B/F co-doped TiO₂ electrode.

Under Fermi level pinning, the two parameters (Vₙc and Vₙb) are linked by eqn (1).

\[ V_{nc} = |V_{fb} - V_{red}| \]  

where Vₙc is the standard reduction potential of a redox couple, assuming that Vₙc does not vary with the addition of boron and nitrogen. Therefore, a higher quasi-Fermi level closer to the conduction band is definitely achieved, which could lead to

![Figure 1](https://example.com/image1.png)

Fig. 1 UV-vis absorption spectra of the bare TiO₂ film, B–F doped TiO₂ film, TiO₂/TGA/CdS-3 film, and B–F-doped TiO₂/TGA/CdS-3 film.
larger $V_{oc}$ for liquid-state QDSSCs employing B/F co-doped TiO$_2$ electrodes. With the co-doping of B/F in TiO$_2$, its band gap was narrowed and the light capture range was significantly extended; the excellent photoelectrochemical performance could be attributed to the ideal combination of retarded electron recombination and superior energy band structure from the unique B/F co-doped TiO$_2$ particle structure.

### 4.3 Device properties

New CdS-functionalized QDSSCs were fabricated in this study in which tetramethyl ammonium sulphide/polydisulphide, ((CH$_4$)$_4$N)$_2$S/((CH$_4$)$_4$N)$_2$S$_n$, was used as the redox couple in an organic solvent (3-methoxy propionitrile (MPN)). The configuration of the cells is illustrated in Scheme 1.

The fill factor (FF) and the overall light-to-electrical energy conversion efficiency ($\eta$) of the DSSC were calculated according to the following equations:

$$\eta(\%) = \frac{V_{oc} \times J_{sc} \times FF}{P_{in}} \times 100\% \quad (2)$$

$$FF = \frac{V_{max} \times J_{max}}{V_{oc} \times J_{sc}} \quad (3)$$

where $P_{in}$ is the incident light power, and $J_{max}$ (mA cm$^{-2}$) and $V_{max}$ (V) are the current density and voltage at the point of the maximum power output in the $J$–$V$ curves, respectively.

The cell based on B–F–TiO$_2$/TGA/CdS-3 photoelectrode was found to give the best performance in this series. Under one sun illumination (AM 1.5G, 100 mW cm$^{-2}$), this cell shows an ideal energy conversion efficiency of 4.74%, a large open-circuit voltage of 1.223 V and an extremely high FF value up to 85.9% with a short-circuit current density ($J_{sc}$) of 4.52 mA cm$^{-2}$; see Fig. 3. Compared with the cell based on TiO$_2$/TGA/CdS-3, the $J_{sc}$ was improved from 3.54 mA cm$^{-2}$ to 4.52 mA cm$^{-2}$, leading to an improvement in efficiencies from 3.45% to 4.74%, and the $V_{oc}$ improved from 1.124 V to 1.223 V; the open-circuit potential of the B–F–TiO$_2$ electrode is negatively shifted by 99 mV compared to the undoped TiO$_2$ electrode, which is consistent with the flat-band potential result. Moreover, using $V_{oc}$ as a reference is a standard way to describe the $J$–$V$ characteristics of an electrochemical cell. $V_{oc}$ is the light intensity dependent rest potential of the cell. Connecting the cell to an electric load causes the electric current to flow in the cell, which gives rise to voltage losses, $V_{h}$, that are also called overpotentials or overvoltages, due to the internal cell resistances $R_{h}$. This decreases the cell voltage from its open-circuit value and determines the shape of the solar cell $J$–$V$ curve and hence its fill factor.

The IPCE (incident photon-to-current conversion efficiency, also referred to as quantum efficiency) of the QDSSCs was determined by measuring the short-circuit current under incident monochromatic light irradiated through a monochromator with a grating of 1200 grooves per mm (Shimadzu Corporation, Kyoto, Japan); light from a xenon lamp passing through a monochromator (PXJ43B11-6W, Japan) was focused onto the cell. The IPCE is calculated according to the following equation:

$$\text{IPCE} = \frac{12400 \times J_{sc}(\text{mA cm}^{-2})}{\lambda(\text{nm}) \times P_{in}(\text{mW cm}^{-2})} \quad (4)$$

where $J_{sc}$ is the short-circuit current density (mA cm$^{-2}$), $V_{oc}$ is the open-circuit voltage (V), $P_{in}$ is the incident light power, and $J_{max}$ (mA cm$^{-2}$) and $V_{max}$ (V) are the current density and voltage in the $J$–$V$ curves, respectively, at the point of the maximum power output.

As shown in Fig. 4, the incident photon-to-electron conversion efficiency spectrum of a B–F–TiO$_2$/TGA/CdS-3 based cell is about 80% in comparison with the TiO$_2$/TGA/CdS-3 based cell, which is over 60% at 400 nm; therefore, the higher IPCE for the QDSC with the B–F–TiO$_2$/TGA/CdS-3 electrode than that with the TiO$_2$/TGA/CdS-3 electrode is due to the B–F doping in the former, and the IPCE response in the visible region is in agreement with the trend for the $J_{sc}$. The active range in the visible light region is consistent with the corresponding UV-vis spectrum. The absorption edge of the B–F–TiO$_2$/TGA/CdS-3-based cell shifts towards longer wavelength of about 30 nm compared to that of TiO$_2$/TGA/CdS-3 based cell.
a modified polysulfide electrolyte in a pure organic system. B/F doping into the TiO₂ lattice results in a red shift of the electronic absorption and enhanced photocurrent response. As a result, the performance of the cell is superb with an efficiency of 4.74%, a significantly high Voc of 1.223 V, and a high FF of 85.9% with a short-circuit photocurrent (Jsc) of 4.52 mA cm⁻². The results show that the combination of B/F co-doped and CdS QD sensitization of the TiO₂ thin films is an effective way to enhance the photoresponse, which is promising for photovoltaic and photoelectrochemical applications.

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Notes and references
